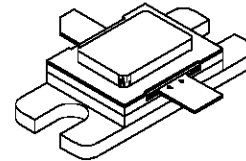


**RF & MICROWAVE TRANSISTORS
AVIONICS APPLICATIONS**

- DESIGNED FOR HIGH POWER PULSED IFF AND DME APPLICATIONS
- 400 (min.) DME 1025 - 1150 MHz
- 6.5 dB MIN. GAIN
- REFRACTORY GOLD METALLIZATION
- EMITTER BALLASTING AND LOW THERMAL RESISTANCE FOR RELIABILITY AND RUGGEDNESS
- 30:1 LOAD VSWR CAPABILITY AT SPECIFIED OPERATING CONDITIONS
- INPUT/OUTPUT MATCHED, COMMON BASE CONFIGURATION



.400 x .500 2LFL (M112)
hermetically sealed

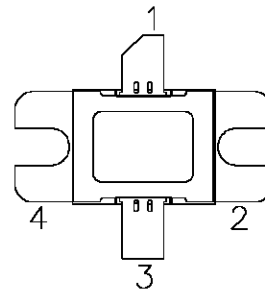
ORDER CODE
SD1541-01

BRANDING
SD1541-1

DESCRIPTION

The SD1541-01 is a hermetically sealed, gold metallized, silicon NPN power transistor. The SD1541-01 is designed for applications requiring high peak power and low duty cycles such as DME. The SD1541-01 is packaged in a hermetic metal/ceramic package with internal input/output matching, resulting in improved broadband performance and a low thermal resistance.

PIN CONNECTION



1. Collector 3. Emitter
2. Base 4. Base

ABSOLUTE MAXIMUM RATINGS ($T_{case} = 25^{\circ}C$)

Symbol	Parameter	Value	Unit
V_{CBO}	Collector-Base Voltage	65	V
V_{CES}	Collector-Emitter Voltage	65	V
V_{EBO}	Emitter-Base Voltage	3.5	V
I_C	Device Current	22	A
P_{DISS}	Power Dissipation	1458	W
T_J	Junction Temperature	+200	$^{\circ}C$
T_{STG}	Storage Temperature	- 65 to +150	$^{\circ}C$

THERMAL DATA

$R_{TH(j-c)}$	Junction-Case Thermal Resistance	0.12	$^{\circ}C/W$
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ELECTRICAL SPECIFICATIONS (T_{case} = 25°C)

STATIC

Symbol	Test Conditions		Value			Unit
			Min.	Typ.	Max.	
BV _{CBO}	I _C = 25mA	I _E = 0mA	65	—	—	V
BV _{CES}	I _C = 50mA	V _{BE} = 0V	65	—	—	V
BV _{EBO}	I _E = 10mA	I _C = 0mA	3.5	—	—	V
I _{CES}	V _{CE} = 50V	I _E = 0mA	—	—	25	mA
h _{FE}	V _{CE} = 5V	I _C = .25A	5	—	200	—

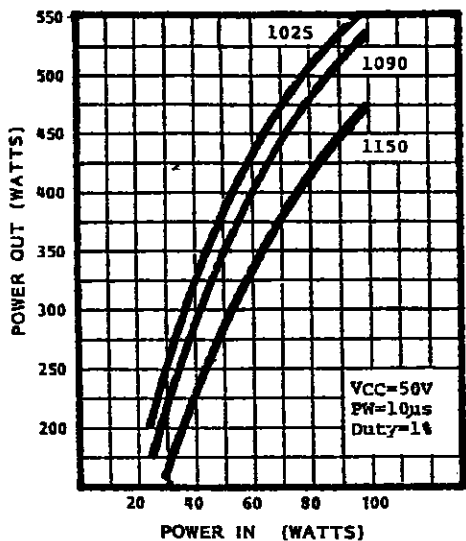
DYNAMIC

Symbol	Test Conditions		Value			Unit
			Min.	Typ.	Max.	
P _{OUT}	f = 1025 — 1150MHz	P _{IN} = 90 W V _{CE} = 50 V	400	—	—	W
G _P	f = 1025 — 1150MHz	P _{IN} = 90 W V _{CE} = 50 V	6.5	—	—	dB

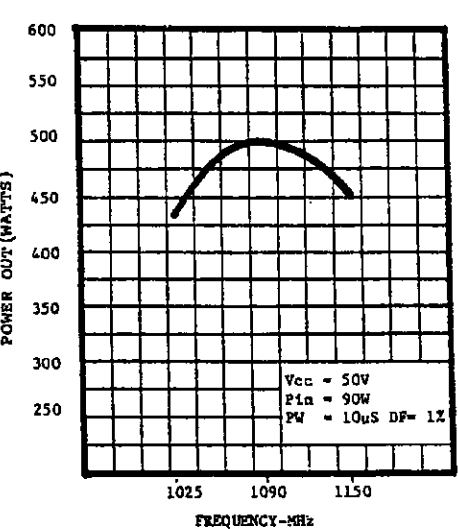
Note: Pulse Width = 10μSec, Duty Cycle = 1%
 This device is suitable for use under other pulse width/duty cycle conditions.
 Please contact the factory for specific applications assistance.

TYPICAL PERFORMANCE

POWER OUTPUT vs POWER INPUT



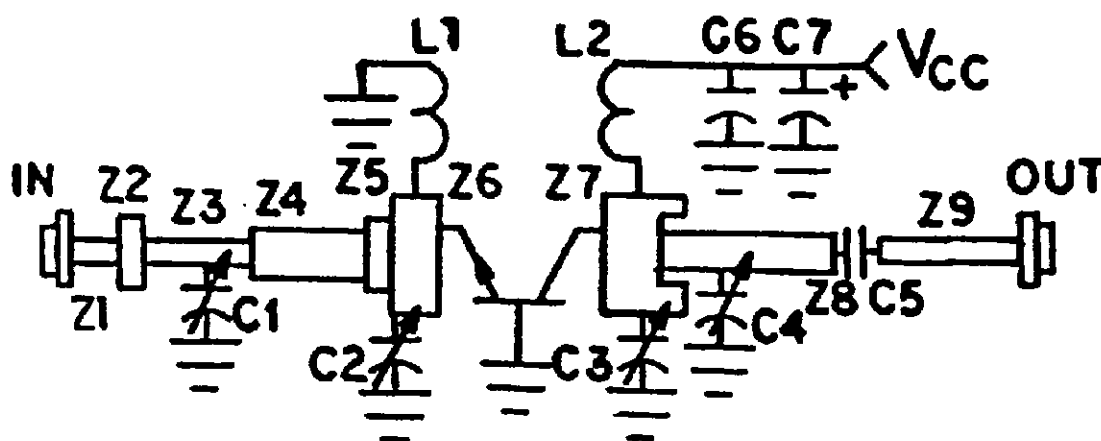
POWER OUTPUT vs FREQUENCY



IMPEDANCE DATA

FREQ.	$Z_{IN} (\Omega)$	$Z_{CL} (\Omega)$
1020 MHz	$2.898 + j 4.1$	$1.382 - j 3.2$
1090 MHz	$2.325 + j 3.4$	$1.338 - j 2.8$
1150 MHz	$1.994 + j 2.8$	$1.269 - j 2.5$

TEST CIRCUIT



All Dimensions in Inches Unless Otherwise specified

C1 : 0.4 - 2.5pF Johanson Gigatrim

C2, C3,

C4 : 0.6 - 4.5pF Johanson Gigatrim

C5 : 82pF Chip Capacitor, .055 Sq.

L1 : Loop, #18 Tinned, .36 Wide x .27 above Circuit

L2 : 4 3/4 Turns, #24 En., C.W., .075 I.D.

Z1 : 50Ω(.02 Wide)

Z2 : .250 x .120

Z3 : 50Ω .020 x .330; C1 tapped .15 from Load

Z4 : .145 x .920

Z5 : .325 x .180

Z6 : .730 x .315

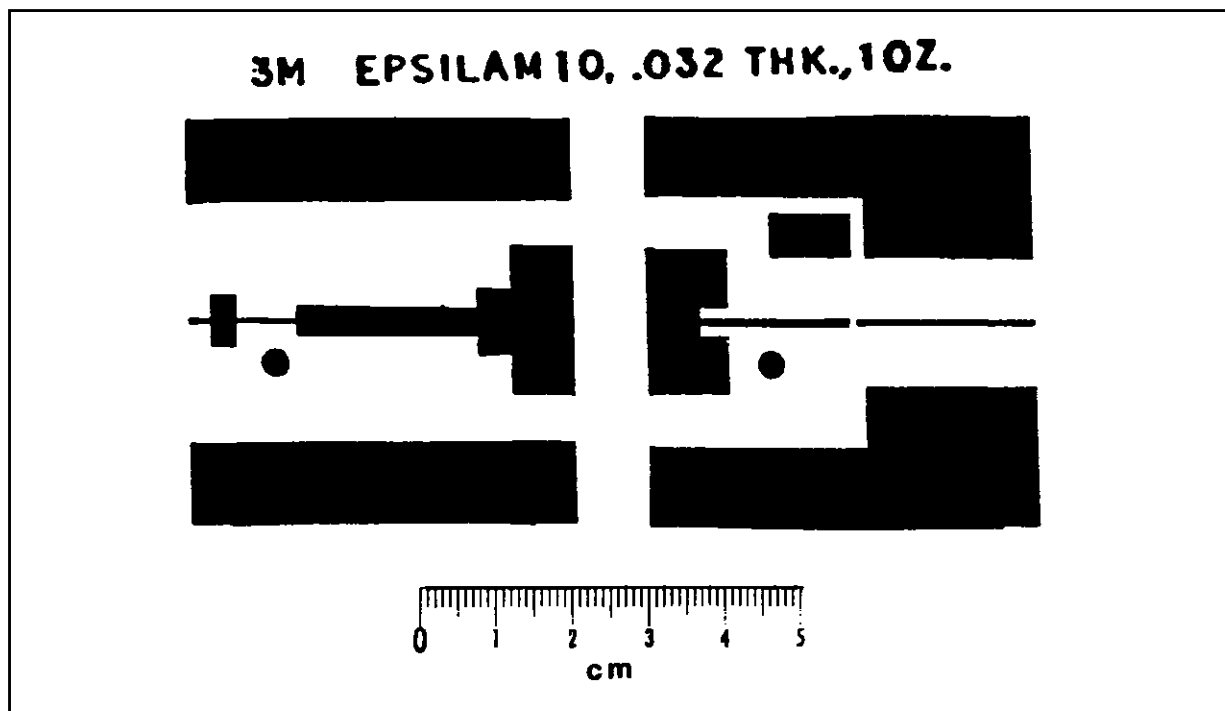
Z7 : .710 x .425 with .140 x .150 cutout

Z8 : .35 x .780; C4 Tapped .36 from Cen

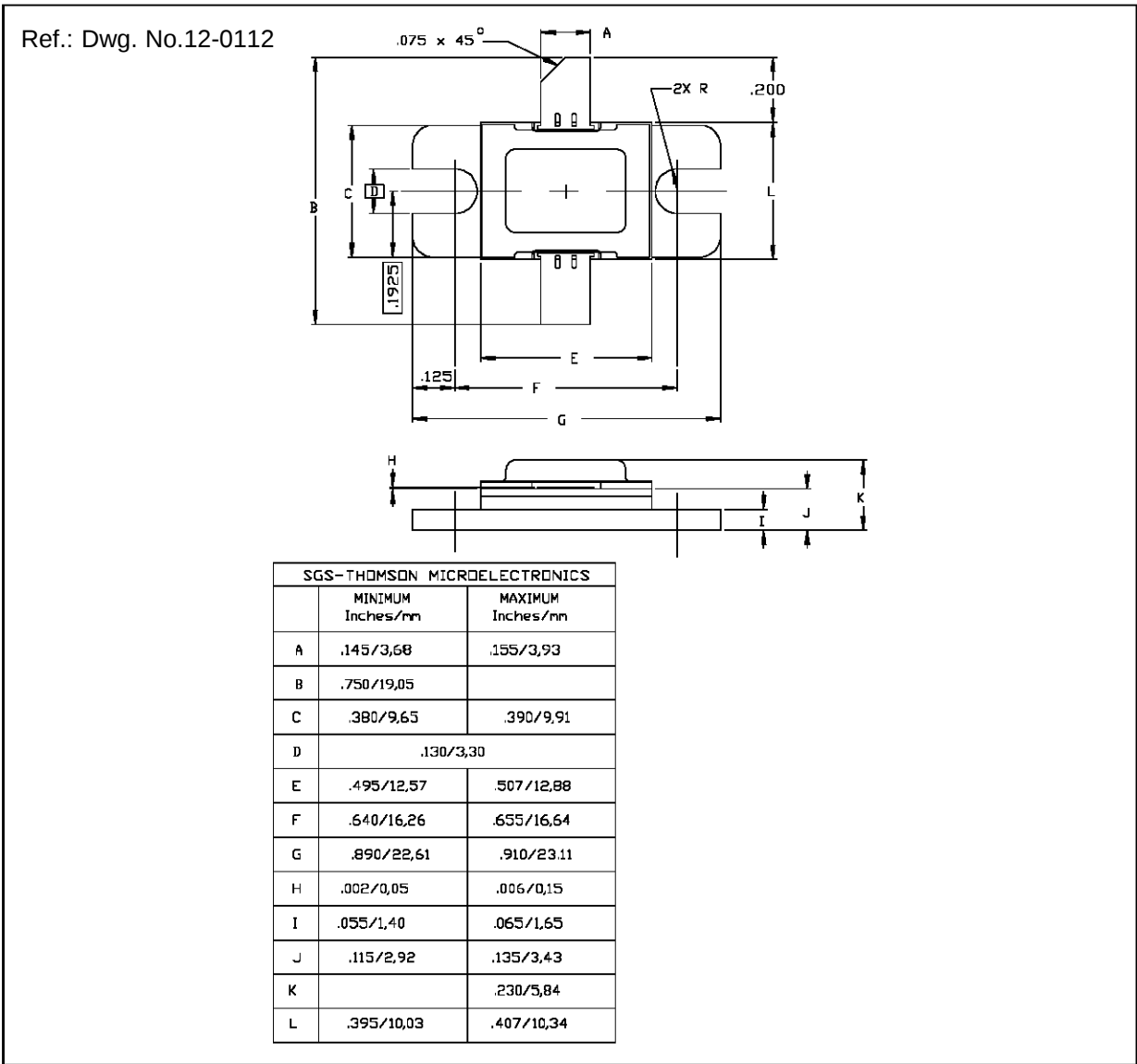
Z9 : 50Ω

C1, C4 : Cold End Terminated Through Eyelet.

PC BOARD LAYOUT



PACKAGE MECHANICAL DATA



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